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APPLICATION NO. FILING DATE FIRST NAMED INVENTOR ATTORNEY DOCKET NO. CONFIRMATION NO. 10/642,959 08/18/2003 Giovanni Santin 400.074US02 4198 7590 06/03/2004 **EXAMINER** FOGG SLIFER & POLGLAZE, P.A. TRAN, MICHAEL THANH Attn: Thomas W. Leffert P.O. Box 581009 ART UNIT PAPER NUMBER Minneapolis, MN 55458-1009 2818

DATE MAILED: 06/03/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)
	10/642,959	SANTIN ET AL.
	Examin r	Art Unit
	Michael T Tran	2818
The MAILING DATE of this communication a Period for Reply	ppears on the cover she t wil	th th correspondence address
A SHORTENED STATUTORY PERIOD FOR REP THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a relative fixed to prevent the maximum statutory perions. - Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the main earned patent term adjustment. See 37 CFR 1.704(b).	J. 1.136(a). In no event, however, may a re eply within the statutory minimum of thirty d will apply and will expire SIX (6) MON tute, cause the application to become AB.	ply be timely filed (30) days will be considered timely. THS from the mailing date of this communication.
Status		
1) Responsive to communication(s) filed on 18	August 2003.	
	nis action is non-final.	
3) Since this application is in condition for allow closed in accordance with the practice under	vance except for formal matte	
Disposition of Claims		
4) ☐ Claim(s) 1-27 is/are pending in the application 4a) Of the above claim(s) is/are withdred is/are withdred is/are allowed. 6) ☐ Claim(s) 1.5,7 and 12 is/are rejected. 7) ☐ Claim(s) 2-4,6,8-11 and 13 is/are objected to 8) ☐ Claim(s) are subject to restriction and	rawn from consideration.	
Application Papers		
9) The specification is objected to by the Examir	ner.	,
10) The drawing(s) filed on is/are: a) □ ac	ccepted or b) objected to b	y the Examiner.
Applicant may not request that any objection to th	e drawing(s) be held in abeyand	ce. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the corre	· · · · · · · · · · · · · · · · · · ·	• • • • • • • • • • • • • • • • • • • •
Priority under 35 U.S.C. § 119		
12) △ Acknowledgment is made of a claim for foreign a) △ All b) ☐ Some * c) ☐ None of: 1. △ Certified copies of the priority document a. ☐ Certified copies of the priority document application from the International Bureat attached detailed Office action for a list	nts have been received. nts have been received in Ap onty documents have been r au (PCT Rule 17.2(a)).	oplication No eceived in this National Stage
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A 11. A 1	M	20
Attachment(s)	, n	W C
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) 🔲 Interview Su Paper No(s)	ımmary (PTO-413) /Mail Date
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date <u>0803</u> .		ormal Patent Application (PTO-152)

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DETAILED ACTION

1. In response to the Communications dated August 18, 2003, claims 1-27 are active in this application.

Foreign Priority

- 2. Receipt is acknowledged of papers submitted under 35 U.S.C. 119(a)
- (d), which papers have been placed of record in the file.

Information Disclosure Statement

3. The information disclosure statement filed August 18, 2003 has been considered.

Claim Objections

4. Claims 1, 5, 7, and 12 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claim Rejections – 35 U.S.C. § 102

5. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

(e) the invention was described in-

(1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effect under this subsection of a national application published under section 122(b) only if the international application designating the United States was published under Article 21(2)(a) of such treaty in the English language; or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that a patent shall not be deemed filed in the United States for the

(2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that a patent shall not be deemed filed in the United States for the purposes of this subsection based on the filing of an international application filed under the treaty defined in section 351(a).

6. Claims 1, 5, 7, and 12 are rejected under 35 U.S.C 102(e) as being anticipated by Hirano [U.S. Patent #6,198,659].

With respect to claim 1, Hirano discloses, in figure 11, a memory device, comprising: an array of floating-gate memory cells [M0-M2], each memory cell located at an intersection of a word line [WL] and a local bit line [BL0-BL2]; a first transistor [Tr] having a first source/drain region coupled to a first potential node [via WL], a second source/drain region coupled to a latch input node [at LAT0-LAT2], and a gate coupled to a first control node [rdpgen]; a second transistor [Tr0-Tr2] having a first source/drain region coupled to the latch input node [at LAT0-LAT2], a second source/drain region coupled to a first local bit line [DL], and a gate coupled to a second control node [bitsel0]; and a fuse latch [LAT0-LAT2] having an input coupled to the latch input node and an output coupled to an output node.

With respect to claim 5, Hirano discloses, in figure 11, that the floating-gate memory cell is an n-channel floating-gate field-effect transistor.

With respect to claim 7, Hirano discloses, in figure 11, that the second transistor is an n-channel field-effect transistor.

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With respect to claim 12, Hirano discloses, in figure 11, that the fuse latch includes a pair of reverse-coupled inverters.

Allowable Subject Matter

- 7. Claims 14-27 are allowable over the prior art of record.
- 8. The following is an Examiner's statement of reasons for the indication of allowable subject matter: the prior art of records does not show (in addition to the other elements in the claim) the following:
 - Wherein a first source/drain region of a first floating-gate memory cell is coupled to the first local bit line, a second source/drain region of the first floating-gate memory cell is coupled to a second potential node, and a gate of the first floatinggate memory cell is coupled to a first word line.
 - Wherein the first transistor is a p-channel field-effect transistor.
 - Wherein the first potential node is coupled to receive a supply potential.
 - ❖ A latch driver circuit capable of setting an output value of the fuse latch without regard to, and without disturbing the data value of, the first floating-gate memory cell.
 - ❖ A fuse latch having an input coupled to the latch input node and an output coupled to the output node; and a second logic circuit having an output coupled to the gate of the fourth field-effect transistor, a first input coupled to the third control node, and a second input coupled to the fourth control node.

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Conclusion

9. When responding to the Office action, Applicants are advised to provide the Examiner with line and page numbers of the application and/or references cited to assist the Examiner in the prosecution of this case.

10. Any inquiry concerning this communication or earlier communications from the Examiner should be directed to Michael T. Tran whose telephone number is (571) 272-1795. The Examiner can normally be reached on Monday-Thursday from 7:30-6:00 P.M.

11. Any inquiry of a general nature or relating to the status of this application should be directed to the Group receptionist whose telephone number is (571) 272-1650.

Michael T. Tran Art Unit 2818 May 28, 2004